July 2015

FDMC7660DC N-Channel Dual Cool[™] 33 PowerTrench[®] MOSFET

30 V, 40 A, 2.2 m Ω

FAIRCHILD

Features

- Dual CoolTM Top Side Cooling PQFN package
- Max $r_{DS(on)}$ = 2.2 m Ω at V_{GS} = 10 V, I_D = 22 A
- Max $r_{DS(on)}$ = 3.3 m Ω at V_{GS} = 4.5 V, I_D = 18 A
- High performance technology for extremely low r_{DS(on)}
- SyncFET Schottky Body Diode
- RoHS Compliant

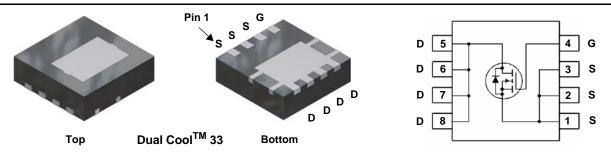


General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench[®] process. Advancements in both silicon and Dual CoolTM package technologies have been combined to offer the lowest $r_{DS(on)}$ while maintaining excellent switching performance by extremely low Junction-to-Ambient thermal resistance.

Applications

- Synchronous Rectifier for DC/DC Converters
- Telecom Secondary Side Rectification
- High End Server/Workstation



MOSFET Maximum Ratings TA= 25°C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			30	V	
V _{GS}	Gate to Source Voltage		(Note 4)	±20	V	
	Drain Current -Continuous (Package limited)	T _C = 25 °C		40		
	-Continuous (Silicon limited)	T _C = 25 °C		150	A	
D	-Continuous	T _A = 25 °C	(Note 1a)	30	A	
	-Pulsed			200		
E _{AS}	Single Pulse Avalanche Energy (1		(Note 3)	220	mJ	
dv/dt	Peak Diode Recovery dv/dt		(Note 5)	1.0	V/ns	
P _D	Power Dissipation	T _C = 25 °C		78	w	
	Power Dissipation	T _A = 25 °C	(Note 1a)	3.0	VV	
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to + 150	°C	

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	(Top Source)	4.3	
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	(Bottom Drain)	1.6	
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1a)	42	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	105	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1i)	17	
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1j)	26	
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient	(Note 1k)	12	

Package Marking and Ordering Information

ſ	Device Marking	Device	Package	Reel Size	Tape Width	Quantity
	7660	FDMC7660DC	Dual Cool TM 33	13"	12 mm	3000 units

DMC76
60DC N
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Cool TM
33 Pow
DMC7660DC N-Channel Dual Cool TM 33 PowerTrench [®] I
h [®] MOS
MOSFET

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		$v_{GS} = 10^{-1} v_{1} I_{D} = 22^{-1} V_{1}$	
r _{DS(on)}	Static Drain to Source On Resistance	66 · D	
		$V_{GS} = 10 \text{ V}, I_D = 22 \text{ A}, T_J = 125^{\circ}\text{C}$	
9 _{FS}	Forward Transconductance	V _{DS} = 5 V, I _D = 22 A	
Dynami	c Characteristics		
C _{iss}	Input Capacitance		
C _{oss}	Output Capacitance	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V},$	
C _{rss}	Reverse Transfer Capacitance	f = 1MHz	
R _g	Gate Resistance		
	ng Characteristics		
	Turn-On Delay Time		
t _{d(on)} t _r	Rise Time		
	Turn-Off Delay Time	V_{DD} = 15 V, I _D = 22 A, V _{GS} = 10 V, R _{GEN} = 6 Ω	
t _{d(off)} t _f	Fall Time		
Q _g	Total Gate Charge	V _{GS} = 0 V to 10 V	
Q _g	Total Gate Charge	$V_{GS} = 0 V \text{ to } 4.5 V V_{DD} = 15 V,$	
Q _{gs}	Gate to Source Charge	$I_{\rm D} = 22 \text{ A}$	
Q _{gd}	Gate to Drain "Miller" Charge		
	Source Drain Diade, Ferward Valtage	$V_{GS} = 0 V, I_S = 22 A$ (Note 2)	
V _{SD}	Source-Drain Diode Forward Voltage	$V_{} = 0 V_{} = 10 \Lambda$ (Note 2)	
		$V_{GS} = 0 V, I_S = 1.9 A$ (Note 2)	
V _{SD}	Reverse Recovery Time	$V_{GS} = 0 V, I_S = 1.9 A$ (Note : 	

Electrical Characteristics T_J = 25°C unless otherwise noted

Test Conditions

 $I_D = 250 \ \mu$ A, referenced to 25 °C

 $I_D = 250 \ \mu A$, referenced to 25 °C

 $I_D = 250 \ \mu\text{A}, \ V_{\text{GS}} = 0 \ \text{V}$

 $V_{DS} = 24 V, V_{GS} = 0 V$ $V_{GS} = 20 V, V_{DS} = 0 V$

 $V_{GS}=V_{DS},\,I_{D}=250~\mu A$

 $V_{GS} = 10 V, I_D = 22 A$

Min

30

1.2

Тур

15

2

-7

1.6

2.5

2.2

147

3885

1215

100

0.7

17

6.6

36

5

54

24

13

5.5

0.8

0.7

43

24

Max

1

100

2.5

2.2

3.3

3.3

5170

1620

150

1.5

31

13

58

10

76

34

1.2

1.2

69

38

Units

V

mV/°C

μΑ

nA

V

mV/°C

mΩ

S

pF

pF

pF

Ω

ns

ns

ns

ns

nC

nC

nC

nC

V

ns

nC

Parameter

Gate to Source Leakage Current, Forward

Drain to Source Breakdown Voltage

Breakdown Voltage Temperature

Zero Gate Voltage Drain Current

Gate to Source Threshold Voltage

Gate to Source Threshold Voltage

Temperature Coefficient

Symbol

 BV_{DSS} $\frac{\Delta BV_{DSS}}{\Delta T_{J}}$

I_{DSS}

I_{GSS}

V_{GS(th)} $\frac{\Delta V_{GS(th)}}{\Delta T_J}$

Off Characteristics

On Characteristics

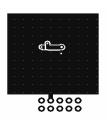
Coefficient

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	(Top Source)	4.3	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	(Bottom Drain)	1.6	
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1a)	42	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	105	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1c)	29	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1d)	40	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1e)	19	00 AM
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1f)	23	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1g)	30	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1h)	79	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1i)	17	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1j)	26	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1k)	12	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1I)	16	

NOTES:

1. R_{0JA} is determined with the device mounted on a FR-4 board using a specified pad of 2 oz copper as shown below. R_{0JC} is guaranteed by design while R_{0CA} is determined by the user's board design.



a. 42 °C/W when mounted on a 1 in² pad of 2 oz copper



b. 105 °C/W when mounted on a minimum pad of 2 oz copper

c. Still air, 20.9x10.4x12.7mm Aluminum Heat Sink, 1 in² pad of 2 oz copper

d. Still air, 20.9x10.4x12.7mm Aluminum Heat Sink, minimum pad of 2 oz copper

e. Still air, 45.2x41.4x11.7mm Aavid Thermalloy Part # 10-L41B-11 Heat Sink, 1 in² pad of 2 oz copper

f. Still air, 45.2x41.4x11.7mm Aavid Thermalloy Part # 10-L41B-11 Heat Sink, minimum pad of 2 oz copper

g. 200FPM Airflow, No Heat Sink,1 in² pad of 2 oz copper

h. 200FPM Airflow, No Heat Sink, minimum pad of 2 oz copper

i. 200FPM Airflow, 20.9x10.4x12.7mm Aluminum Heat Sink, 1 in² pad of 2 oz copper

j. 200FPM Airflow, 20.9x10.4x12.7mm Aluminum Heat Sink, minimum pad of 2 oz copper

k. 200FPM Airflow, 45.2x41.4x11.7mm Aavid Thermalloy Part # 10-L41B-11 Heat Sink, 1 in² pad of 2 oz copper

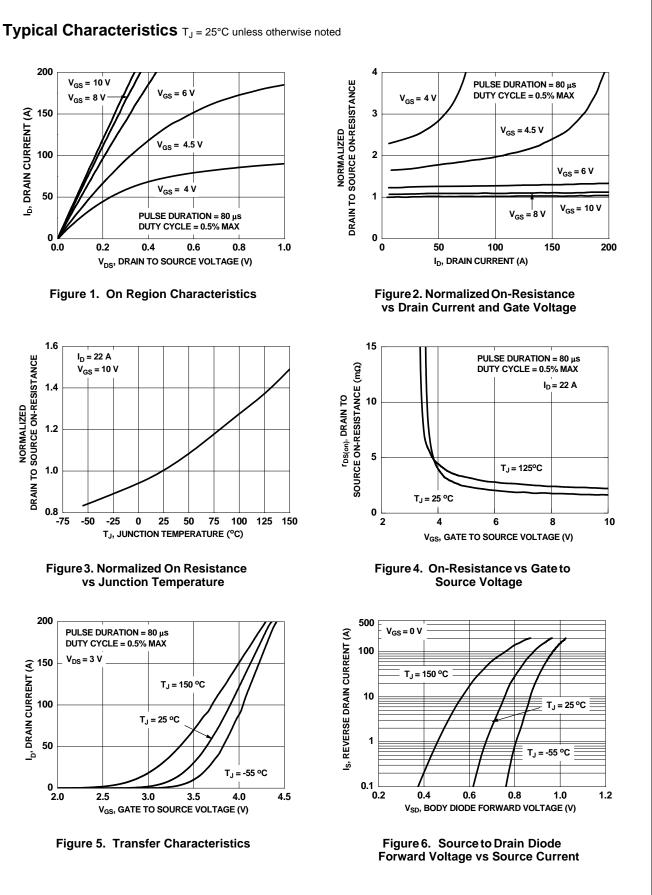
I. 200FPM Airflow, 45.2x41.4x11.7mm Aavid Thermalloy Part # 10-L41B-11 Heat Sink, minimum pad of 2 oz copper

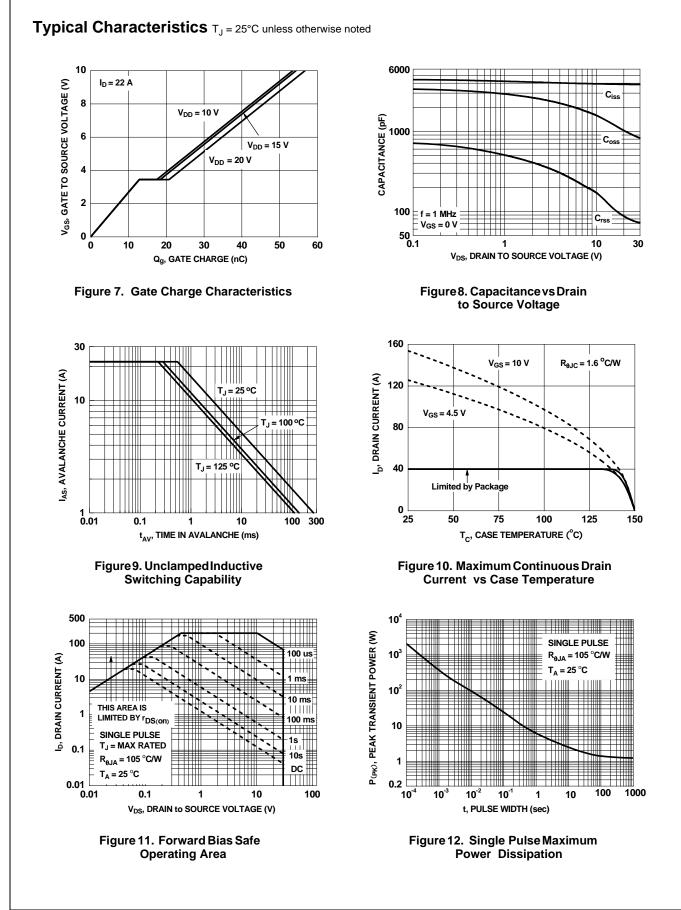
2. Pulse Test: Pulse Width < 300 μ s, Duty cycle < 2.0%.

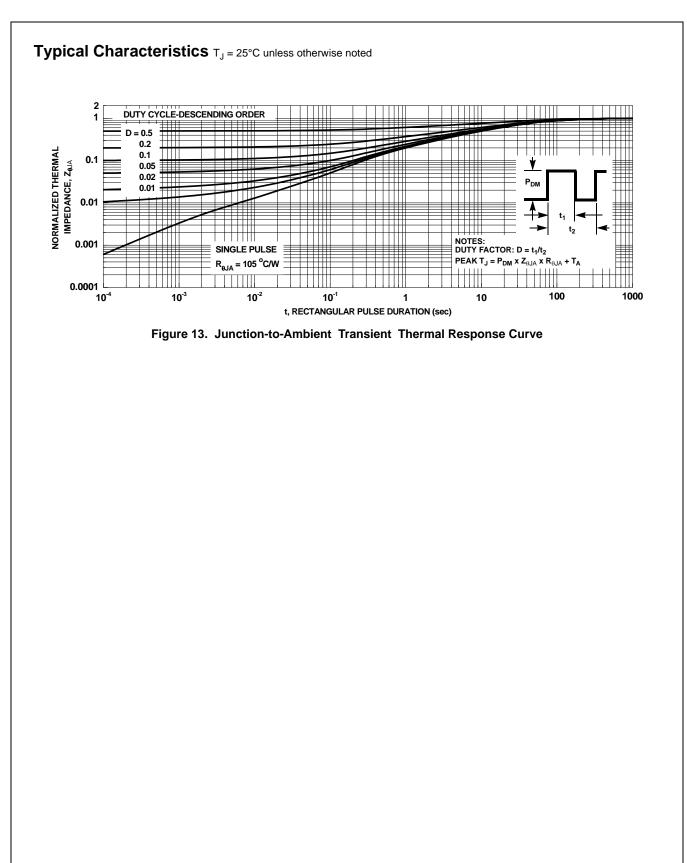
3. E_{AS} of 220 mJ is based on starting T_J = 25 $^{\circ}$ C; N-ch: L = 1 mH, I_{AS} = 21 A, V_{DD} = 27 V, V_{GS} = 10 V. 100% test at L = 0.3 mH, I_{AS} = 33.5 A.

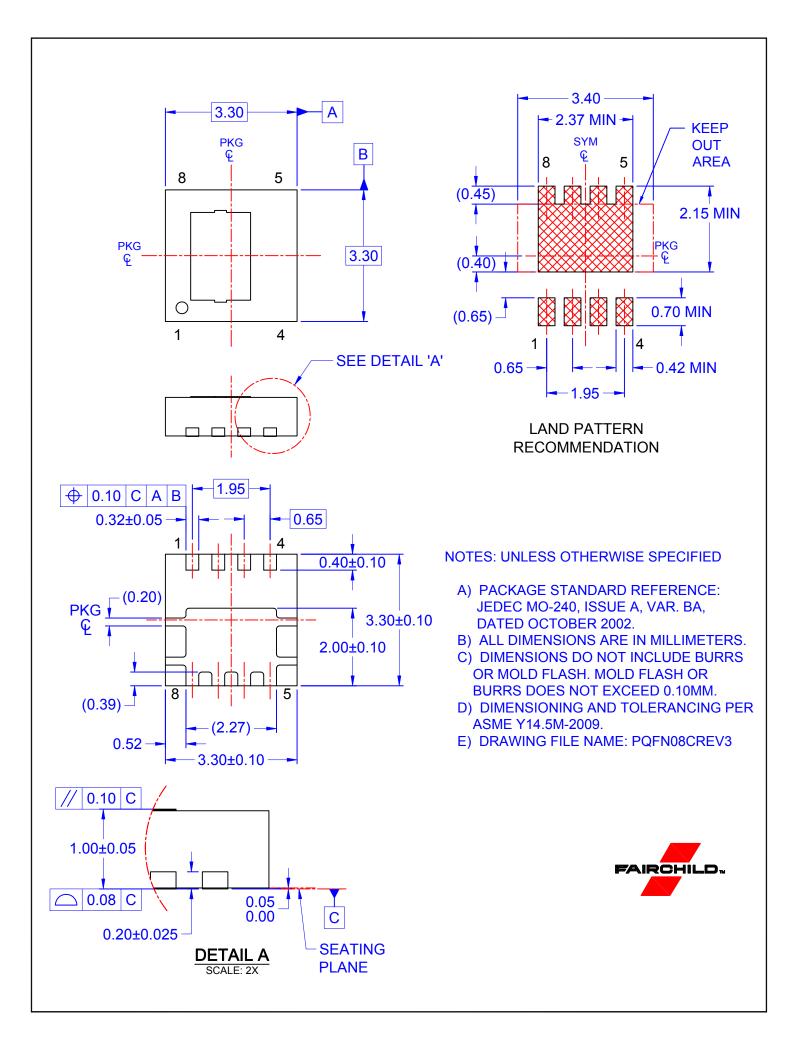
4. As an N-ch device, the negative Vgs rating is for low duty cycle pulse ocurrence only. No continuous rating is implied.

5. $I_{SD} \leq$ 22 A, di/dt \leq 100 A/µs, $V_{DD} \leq BV_{DSS},~$ Starting T_J = 25 °C.











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